## NSN 5961-00-855-3727

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View Online at https://aerobasegroup.com/nsn/5961-00-855-3727 **Inclosure Material:** Metal **Overall Length:** 0.180 inches **Terminal Length:** 1.500 inches **Overall Diameter:** 0.335 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-base, emitter open all transistor and 30.0 breakdown voltage, collector-to-emitter, base open all transistor and 5.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 800.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 800.0 milliwatts small-signal input power, common-collector absolute all transistor **Transfer Ratio:** 25.0 small-signal short-circuit forward current transfer ratio, common-emitter all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Internal junction configuration transistor npn **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a

No

**Unit Of Measure:** 

Demilitarization:

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